

26 HAL FLASH Generic Driver

26.1 FLASH Firmware driver registers structures

26.1.1 FLASH_ProcessTypeDef

 $\textit{FLASH_ProcessTypeDef} \text{ is defined in the stm} 32 \text{f4xx_hal_flash.h}$

Data Fields

- __IO FLASH_ProcedureTypeDef ProcedureOnGoing
- IO uint32 t NbSectorsToErase
- IO uint8 t VoltageForErase
- __IO uint32_t Sector
- __IO uint32_t Bank
- IO uint32_t Address
- HAL LockTypeDef Lock
- __IO uint32_t ErrorCode

Field Documentation

- IO FLASH ProcedureTypeDef FLASH ProcessTypeDef::ProcedureOnGoing
- __IO uint32_t FLASH_ProcessTypeDef::NbSectorsToErase
- __IO uint8_t FLASH_ProcessTypeDef::VoltageForErase
- __IO uint32_t FLASH_ProcessTypeDef::Sector
- __IO uint32_t FLASH_ProcessTypeDef::Bank
- IO uint32 t FLASH ProcessTypeDef::Address
- HAL LockTypeDef FLASH ProcessTypeDef::Lock
- __IO uint32_t FLASH_ProcessTypeDef::ErrorCode

26.2 FLASH Firmware driver API description

The following section lists the various functions of the FLASH library.

26.2.1 FLASH peripheral features

The Flash memory interface manages CPU AHB I-Code and D-Code accesses to the Flash memory. It implements the erase and program Flash memory operations and the read and write protection mechanisms.

The Flash memory interface accelerates code execution with a system of instruction prefetch and cache lines.

The FLASH main features are:

- Flash memory read operations
- Flash memory program/erase operations
- Read / write protections
- · Prefetch on I-Code
- 64 cache lines of 128 bits on I-Code
- 8 cache lines of 128 bits on D-Code

26.2.2 How to use this driver

This driver provides functions and macros to configure and program the FLASH memory of all STM32F4xx devices.

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- 1. FLASH Memory IO Programming functions:
 - Lock and Unlock the FLASH interface using HAL_FLASH_Unlock() and HAL_FLASH_Lock() functions
 - Program functions: byte, half word, word and double word
 - There Two modes of programming :
 - Polling mode using HAL_FLASH_Program() function
 - Interrupt mode using HAL_FLASH_Program_IT() function
- 2. Interrupts and flags management functions :
 - Handle FLASH interrupts by calling HAL_FLASH_IRQHandler()
 - Wait for last FLASH operation according to its status
 - Get error flag status by calling HAL_SetErrorCode()

In addition to these functions, this driver includes a set of macros allowing to handle the following operations:

- Set the latency
- Enable/Disable the prefetch buffer
- Enable/Disable the Instruction cache and the Data cache
- Reset the Instruction cache and the Data cache
- Enable/Disable the FLASH interrupts
- · Monitor the FLASH flags status

26.2.3 Programming operation functions

This subsection provides a set of functions allowing to manage the FLASH program operations.

This section contains the following APIs:

- HAL FLASH Program()
- HAL_FLASH_Program_IT()
- HAL_FLASH_IRQHandler()
- HAL_FLASH_EndOfOperationCallback()
- HAL_FLASH_OperationErrorCallback()

26.2.4 Peripheral Control functions

This subsection provides a set of functions allowing to control the FLASH memory operations.

This section contains the following APIs:

- HAL FLASH Unlock()
- HAL FLASH Lock()
- HAL_FLASH_OB_Unlock()
- HAL FLASH OB Lock()
- HAL_FLASH_OB_Launch()

26.2.5 Peripheral Errors functions

This subsection permits to get in run-time Errors of the FLASH peripheral.

This section contains the following APIs:

- HAL_FLASH_GetError()
- FLASH_WaitForLastOperation()

26.2.6 Detailed description of functions

HAL_FLASH_Program

Function name

HAL_StatusTypeDef HAL_FLASH_Program (uint32_t TypeProgram, uint32_t Address, uint64_t Data)

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Function description

Program byte, halfword, word or double word at a specified address.

Parameters

- TypeProgram: Indicate the way to program at a specified address. This parameter can be a value of FLASH Type Program
- Address: specifies the address to be programmed.
- Data: specifies the data to be programmed

Return values

HAL_StatusTypeDef: HAL Status

HAL_FLASH_Program_IT

Function name

HAL_StatusTypeDef HAL_FLASH_Program_IT (uint32_t TypeProgram, uint32_t Address, uint64_t Data)

Function description

Program byte, halfword, word or double word at a specified address with interrupt enabled.

Parameters

- TypeProgram: Indicate the way to program at a specified address. This parameter can be a value of FLASH Type Program
- Address: specifies the address to be programmed.
- Data: specifies the data to be programmed

Return values

HAL: Status

HAL_FLASH_IRQHandler

Function name

void HAL_FLASH_IRQHandler (void)

Function description

This function handles FLASH interrupt request.

Return values

None:

HAL_FLASH_EndOfOperationCallback

Function name

void HAL_FLASH_EndOfOperationCallback (uint32_t ReturnValue)

Function description

FLASH end of operation interrupt callback.

Parameters

ReturnValue: The value saved in this parameter depends on the ongoing procedure Mass Erase:
 Bank number which has been requested to erase Sectors Erase: Sector which has been erased (if 0xFFFFFFFU, it means that all the selected sectors have been erased) Program: Address which was selected for data program

Return values

None:

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HAL_FLASH_OperationErrorCallback

Function name

void HAL_FLASH_OperationErrorCallback (uint32_t ReturnValue)

Function description

FLASH operation error interrupt callback.

Parameters

• **ReturnValue:** The value saved in this parameter depends on the ongoing procedure Mass Erase: Bank number which has been requested to erase Sectors Erase: Sector number which returned an error Program: Address which was selected for data program

Return values

None:

HAL_FLASH_Unlock

Function name

HAL_StatusTypeDef HAL_FLASH_Unlock (void)

Function description

Unlock the FLASH control register access.

Return values

HAL: Status

HAL_FLASH_Lock

Function name

HAL_StatusTypeDef HAL_FLASH_Lock (void)

Function description

Locks the FLASH control register access.

Return values

HAL: Status

HAL_FLASH_OB_Unlock

Function name

HAL_StatusTypeDef HAL_FLASH_OB_Unlock (void)

Function description

Unlock the FLASH Option Control Registers access.

Return values

HAL: Status

HAL_FLASH_OB_Lock

Function name

HAL_StatusTypeDef HAL_FLASH_OB_Lock (void)

Function description

Lock the FLASH Option Control Registers access.

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Return values

HAL: Status

HAL_FLASH_OB_Launch

Function name

HAL_StatusTypeDef HAL_FLASH_OB_Launch (void)

Function description

Launch the option byte loading.

Return values

HAL: Status

HAL_FLASH_GetError

Function name

uint32_t HAL_FLASH_GetError (void)

Function description

Get the specific FLASH error flag.

Return values

- FLASH_ErrorCode: The returned value can be a combination of:
 - HAL FLASH ERROR RD: FLASH Read Protection error flag (PCROP)
 - HAL_FLASH_ERROR_PGS: FLASH Programming Sequence error flag
 - HAL_FLASH_ERROR_PGP: FLASH Programming Parallelism error flag
 - HAL_FLASH_ERROR_PGA: FLASH Programming Alignment error flag
 - HAL_FLASH_ERROR_WRP: FLASH Write protected error flag
 - HAL_FLASH_ERROR_OPERATION: FLASH operation Error flag

FLASH_WaitForLastOperation

Function name

HAL_StatusTypeDef FLASH_WaitForLastOperation (uint32_t Timeout)

Function description

Wait for a FLASH operation to complete.

Parameters

Timeout: maximum flash operationtimeout

Return values

HAL: Status

26.3 FLASH Firmware driver defines

The following section lists the various define and macros of the module.

26.3.1 FLASH

FLASH

FLASH Error Code

HAL_FLASH_ERROR_NONE

No error

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HAL FLASH ERROR RD

Read Protection error

HAL_FLASH_ERROR_PGS

Programming Sequence error

HAL_FLASH_ERROR_PGP

Programming Parallelism error

HAL_FLASH_ERROR_PGA

Programming Alignment error

HAL_FLASH_ERROR_WRP

Write protection error

HAL_FLASH_ERROR_OPERATION

Operation Error

FLASH Exported Macros

__HAL_FLASH_SET_LATENCY

Description:

Set the FLASH Latency.

Parameters:

 __LATENCY__: FLASH Latency The value of this parameter depend on device used within the same series

Return value:

none

__HAL_FLASH_GET_LATENCY

Description:

Get the FLASH Latency.

Return value:

FLASH: Latency The value of this parameter depend on device used within the same series

HAL_FLASH_PREFETCH_BUFFER_ENABLE

Description:

Enable the FLASH prefetch buffer.

Return value:

none

__HAL_FLASH_PREFETCH_BUFFER_DISABLE

Description:

Disable the FLASH prefetch buffer.

Return value:

none

__HAL_FLASH_INSTRUCTION_CACHE_ENABLE

Description:

Enable the FLASH instruction cache.

Return value:

none

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__HAL_FLASH_INSTRUCTION_CACHE_DISABLE

Description:

Disable the FLASH instruction cache.

Return value:

none

__HAL_FLASH_DATA_CACHE_ENABLE

Description:

Enable the FLASH data cache.

Return value:

none

__HAL_FLASH_DATA_CACHE_DISABLE

Description:

Disable the FLASH data cache.

Return value:

none

__HAL_FLASH_INSTRUCTION_CACHE_RESET

Description:

Resets the FLASH instruction Cache.

Return value:

None

Notes:

• This function must be used only when the Instruction Cache is disabled.

__HAL_FLASH_DATA_CACHE_RESET

Description:

Resets the FLASH data Cache.

Return value:

None

Notes:

This function must be used only when the data Cache is disabled.

__HAL_FLASH_ENABLE_IT

Description:

Enable the specified FLASH interrupt.

Parameters:

- __INTERRUPT__: FLASH interrupt This parameter can be any combination of the following values:
 - FLASH IT EOP: End of FLASH Operation Interrupt
 - FLASH_IT_ERR: Error Interrupt

Return value:

none

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__HAL_FLASH_DISABLE_IT

Description:

Disable the specified FLASH interrupt.

Parameters:

- INTERRUPT : FLASH interrupt This parameter can be any combination of the following values:
 - FLASH IT EOP: End of FLASH Operation Interrupt
 - FLASH IT ERR: Error Interrupt

Return value:

none

__HAL_FLASH_GET_FLAG

Description:

Get the specified FLASH flag status.

Parameters:

- __FLAG__: specifies the FLASH flags to check. This parameter can be any combination of the following values:
 - FLASH_FLAG_EOP : FLASH End of Operation flag
 - FLASH_FLAG_OPERR: FLASH operation Error flag
 - FLASH FLAG WRPERR: FLASH Write protected error flag
 - FLASH FLAG PGAERR: FLASH Programming Alignment error flag
 - FLASH_FLAG_PGPERR: FLASH Programming Parallelism error flag
 - FLASH FLAG PGSERR: FLASH Programming Sequence error flag
 - FLASH FLAG RDERR: FLASH Read Protection error flag (PCROP) (*)
 - FLASH_FLAG_BSY: FLASH Busy flag (*) FLASH_FLAG_RDERR is not available for STM32F405xx/407xx/415xx/417xx devices

Return value:

The: new state of __FLAG__ (SET or RESET).

__HAL_FLASH_CLEAR_FLAG

Description:

Clear the specified FLASH flags.

Parameters:

- __FLAG__: specifies the FLASH flags to clear. This parameter can be any combination of the following values:
 - FLASH_FLAG_EOP : FLASH End of Operation flag
 - FLASH FLAG OPERR: FLASH operation Error flag
 - FLASH FLAG WRPERR: FLASH Write protected error flag
 - FLASH_FLAG_PGAERR: FLASH Programming Alignment error flag
 - FLASH_FLAG_PGPERR: FLASH Programming Parallelism error flag
 - FLASH_FLAG_PGSERR: FLASH Programming Sequence error flag
 - FLASH_FLAG_RDERR: FLASH Read Protection error flag (PCROP) (*) (*) FLASH_FLAG_RDERR is not available for STM32F405xx/407xx/415xx/417xx devices

Return value:

none

FLASH Flag definition

FLASH_FLAG_EOP

FLASH End of Operation flag

FLASH_FLAG_OPERR

FLASH operation Error flag

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FLASH FLAG WRPERR

FLASH Write protected error flag

FLASH_FLAG_PGAERR

FLASH Programming Alignment error flag

FLASH_FLAG_PGPERR

FLASH Programming Parallelism error flag

FLASH_FLAG_PGSERR

FLASH Programming Sequence error flag

FLASH_FLAG_RDERR

Read Protection error flag (PCROP)

FLASH_FLAG_BSY

FLASH Busy flag

FLASH Interrupt definition

FLASH_IT_EOP

End of FLASH Operation Interrupt source

FLASH_IT_ERR

Error Interrupt source

FLASH Private macros to check input parameters

IS_FLASH_TYPEPROGRAM

FLASH Keys

RDP_KEY

FLASH_KEY1

FLASH_KEY2

FLASH_OPT_KEY1

FLASH_OPT_KEY2

FLASH Latency

FLASH_LATENCY_0

FLASH Zero Latency cycle

FLASH_LATENCY_1

FLASH One Latency cycle

FLASH_LATENCY_2

FLASH Two Latency cycles

FLASH_LATENCY_3

FLASH Three Latency cycles

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FLASH_LATENCY_4

FLASH Four Latency cycles

FLASH_LATENCY_5

FLASH Five Latency cycles

FLASH_LATENCY_6

FLASH Six Latency cycles

FLASH_LATENCY_7

FLASH Seven Latency cycles

FLASH_LATENCY_8

FLASH Eight Latency cycles

FLASH_LATENCY_9

FLASH Nine Latency cycles

FLASH_LATENCY_10

FLASH Ten Latency cycles

FLASH_LATENCY_11

FLASH Eleven Latency cycles

FLASH_LATENCY_12

FLASH Twelve Latency cycles

FLASH_LATENCY_13

FLASH Thirteen Latency cycles

FLASH_LATENCY_14

FLASH Fourteen Latency cycles

FLASH_LATENCY_15

FLASH Fifteen Latency cycles

FLASH Program Parallelism

FLASH_PSIZE_BYTE

FLASH_PSIZE_HALF_WORD

FLASH_PSIZE_WORD

FLASH_PSIZE_DOUBLE_WORD

CR_PSIZE_MASK

FLASH Type Program

FLASH_TYPEPROGRAM_BYTE

Program byte (8-bit) at a specified address

FLASH_TYPEPROGRAM_HALFWORD

Program a half-word (16-bit) at a specified address

FLASH_TYPEPROGRAM_WORD

Program a word (32-bit) at a specified address

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FLASH_TYPEPROGRAM_DOUBLEWORD

Program a double word (64-bit) at a specified address

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27 HAL FLASH Extension Driver

27.1 FLASHEx Firmware driver registers structures

27.1.1 FLASH_EraseInitTypeDef

 $\textit{FLASH_EraseInitTypeDef} \ is \ defined \ in \ the \ stm32f4xx_hal_flash_ex.h$

Data Fields

- uint32_t TypeErase
- uint32 t Banks
- uint32 t Sector
- uint32_t NbSectors
- uint32_t VoltageRange

Field Documentation

uint32_t FLASH_EraseInitTypeDef::TypeErase
 Mass erase or sector Erase. This parameter can be a value of FLASHEx Type Erase

uint32_t FLASH_EraseInitTypeDef::Banks

Select banks to erase when Mass erase is enabled. This parameter must be a value of FLASHEX Banks

uint32_t FLASH_EraseInitTypeDef::Sector
 Initial FLASH sector to erase when Mass erase is disabled This parameter must be a value of FLASHEx_Sectors

uint32 t FLASH EraseInitTypeDef::NbSectors

Number of sectors to be erased. This parameter must be a value between 1 and (max number of sectors - value of Initial sector)

uint32_t FLASH_EraseInitTypeDef::VoltageRange
 The device voltage range which defines the erase parallelism This parameter must be a value of FLASHEx_Voltage_Range

27.1.2 FLASH_OBProgramInitTypeDef

FLASH OBProgramInitTypeDef is defined in the stm32f4xx_hal_flash_ex.h

Data Fields

- uint32_t OptionType
- uint32 t WRPState
- uint32 t WRPSector
- uint32_t Banks
- uint32 t RDPLevel
- uint32 t BORLevel
- uint8_t USERConfig

Field Documentation

uint32_t FLASH_OBProgramInitTypeDef::OptionType

Option byte to be configured. This parameter can be a value of FLASHEx_Option_Type

uint32 t FLASH OBProgramInitTypeDef::WRPState

Write protection activation or deactivation. This parameter can be a value of FLASHEx_WRP_State

uint32_t FLASH_OBProgramInitTypeDef::WRPSector

Specifies the sector(s) to be write protected. The value of this parameter depend on device used within the same series

uint32 t FLASH OBProgramInitTypeDef::Banks

Select banks for WRP activation/deactivation of all sectors. This parameter must be a value of **FLASHEX Banks**

uint32_t FLASH_OBProgramInitTypeDef::RDPLevel
 Set the read protection level. This parameter can be a value of FLASHEx Option Bytes Read Protection

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- uint32_t FLASH_OBProgramInitTypeDef::BORLevel
 Set the BOR Level. This parameter can be a value of FLASHEx BOR Reset Level
- uint8_t FLASH_OBProgramInitTypeDef::USERConfig
 Program the FLASH User Option Byte: IWDG_SW / RST_STOP / RST_STDBY.

27.1.3 FLASH_AdvOBProgramInitTypeDef

FLASH_AdvOBProgramInitTypeDef is defined in the stm32f4xx_hal_flash_ex.h **Data Fields**

- uint32_t OptionType
- uint32 t PCROPState
- uint32 t Banks
- uint16 t SectorsBank1
- uint16 t SectorsBank2
- uint8_t BootConfig

Field Documentation

- uint32_t FLASH_AdvOBProgramInitTypeDef::OptionType
 Option byte to be configured for extension. This parameter can be a value of FLASHEx Advanced Option Type
- uint32_t FLASH_AdvOBProgramInitTypeDef::PCROPState
 PCROP activation or deactivation. This parameter can be a value of FLASHEx_PCROP_State
- uint32_t FLASH_AdvOBProgramInitTypeDef::Banks
 Select banks for PCROP activation/deactivation of all sectors. This parameter must be a value of FLASHEx_Banks
- uint16_t FLASH_AdvOBProgramInitTypeDef::SectorsBank1
 Specifies the sector(s) set for PCROP for Bank1. This parameter can be a value of FLASHEX Option Bytes PC ReadWrite Protection
- uint16_t FLASH_AdvOBProgramInitTypeDef::SectorsBank2
 Specifies the sector(s) set for PCROP for Bank2. This parameter can be a value of FLASHEx_Option_Bytes_PC_ReadWrite_Protection
- uint8_t FLASH_AdvOBProgramInitTypeDef::BootConfig
 Specifies Option bytes for boot config. This parameter can be a value of FLASHEx Dual Boot

27.2 FLASHEx Firmware driver API description

The following section lists the various functions of the FLASHEx library.

27.2.1 Flash Extension features

Comparing to other previous devices, the FLASH interface for STM32F427xx/437xx and STM32F429xx/439xx devices contains the following additional features

- Capacity up to 2 Mbyte with dual bank architecture supporting read-while-write capability (RWW)
- Dual bank memory organization
- · PCROP protection for all banks

27.2.2 How to use this driver

This driver provides functions to configure and program the FLASH memory of all STM32F427xx/437xx, STM32F429xx/439xx, STM32F469xx/479xx and STM32F446xx devices. It includes

- FLASH Memory Erase functions:
 - Lock and Unlock the FLASH interface using HAL_FLASH_Unlock() and HAL_FLASH_Lock() functions
 - Erase function: Erase sector, erase all sectors
 - There are two modes of erase :
 - Polling Mode using HAL_FLASHEx_Erase()
 - Interrupt Mode using HAL_FLASHEx_Erase_IT()

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- 2. Option Bytes Programming functions: Use HAL FLASHEx OBProgram() to :
 - Set/Reset the write protection
 - Set the Read protection Level
 - Set the BOR level
 - Program the user Option Bytes
- 3. Advanced Option Bytes Programming functions: Use HAL_FLASHEx_AdvOBProgram() to :
 - Extended space (bank 2) erase function
 - Full FLASH space (2 Mo) erase (bank 1 and bank 2)
 - Dual Boot activation
 - Write protection configuration for bank 2
 - PCROP protection configuration and control for both banks

27.2.3 Extended programming operation functions

This subsection provides a set of functions allowing to manage the Extension FLASH programming operations. This section contains the following APIs:

- HAL FLASHEX Erase()
- HAL FLASHEX Erase IT()
- HAL FLASHEX OBProgram()
- HAL_FLASHEx_OBGetConfig()
- HAL_FLASHEx_AdvOBProgram()
- HAL FLASHEx AdvOBGetConfig()
- HAL FLASHEX OB SelectPCROP()
- HAL FLASHEX OB DeSelectPCROP()
- HAL_FLASHEx_OB_GetBank2WRP()

27.2.4 Detailed description of functions

HAL_FLASHEx_Erase

Function name

HAL_StatusTypeDef HAL_FLASHEx_Erase (FLASH_EraseInitTypeDef * pEraseInit, uint32_t * SectorError)

Function description

Perform a mass erase or erase the specified FLASH memory sectors.

Parameters

- **pEraseInit:** pointer to an FLASH_EraseInitTypeDef structure that contains the configuration information for the erasing.
- **SectorError:** pointer to variable that contains the configuration information on faulty sector in case of error (0xFFFFFFFU means that all the sectors have been correctly erased)

Return values

HAL: Status

HAL FLASHEX Erase IT

Function name

HAL_StatusTypeDef HAL_FLASHEx_Erase_IT (FLASH_EraseInitTypeDef * pEraseInit)

Function description

Perform a mass erase or erase the specified FLASH memory sectors with interrupt enabled.

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Parameters

• **pEraseInit:** pointer to an FLASH_EraseInitTypeDef structure that contains the configuration information for the erasing.

Return values

HAL: Status

HAL_FLASHEx_OBProgram

Function name

HAL_StatusTypeDef HAL_FLASHEx_OBProgram (FLASH_OBProgramInitTypeDef * pOBInit)

Function description

Program option bytes.

Parameters

 pOBInit: pointer to an FLASH_OBInitStruct structure that contains the configuration information for the programming.

Return values

HAL: Status

HAL_FLASHEx_OBGetConfig

Function name

void HAL_FLASHEx_OBGetConfig (FLASH_OBProgramInitTypeDef * pOBInit)

Function description

Get the Option byte configuration.

Parameters

 pOBInit: pointer to an FLASH_OBInitStruct structure that contains the configuration information for the programming.

Return values

None:

HAL_FLASHEx_AdvOBProgram

Function name

HAL_StatusTypeDef HAL_FLASHEx_AdvOBProgram (FLASH_AdvOBProgramInitTypeDef * pAdvOBInit)

Function description

Program option bytes.

Parameters

• **pAdvOBInit:** pointer to an FLASH_AdvOBProgramInitTypeDef structure that contains the configuration information for the programming.

Return values

HAL: Status

HAL_FLASHEx_AdvOBGetConfig

Function name

void HAL_FLASHEx_AdvOBGetConfig (FLASH_AdvOBProgramInitTypeDef * pAdvOBInit)

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Function description

Get the OBEX byte configuration.

Parameters

• **pAdvOBInit:** pointer to an FLASH_AdvOBProgramInitTypeDef structure that contains the configuration information for the programming.

Return values

None:

HAL_FLASHEx_OB_SelectPCROP

Function name

HAL_StatusTypeDef HAL_FLASHEx_OB_SelectPCROP (void)

Function description

Select the Protection Mode.

Return values

HAL: Status

Notes

- After PCROP activated Option Byte modification NOT POSSIBLE! excepted Global Read Out Protection modification (from level1 to level0)
- Once SPRMOD bit is active unprotection of a protected sector is not possible
- Read a protected sector will set RDERR Flag and write a protected sector will set WRPERR Flag
- This function can be used only for STM32F42xxx/STM32F43xxx/STM32F401xx/STM32F411xx/ STM32F446xx/ STM32F469xx/STM32F479xx/STM32F412xx/STM32F413xx devices.

HAL_FLASHEx_OB_DeSelectPCROP

Function name

HAL_StatusTypeDef HAL_FLASHEx_OB_DeSelectPCROP (void)

Function description

Deselect the Protection Mode.

Return values

HAL: Status

Notes

- After PCROP activated Option Byte modification NOT POSSIBLE! excepted Global Read Out Protection modification (from level1 to level0)
- Once SPRMOD bit is active unprotection of a protected sector is not possible
- Read a protected sector will set RDERR Flag and write a protected sector will set WRPERR Flag
- This function can be used only for STM32F42xxx/STM32F43xxx/STM32F401xx/STM32F411xx/ STM32F446xx/ STM32F469xx/STM32F479xx/STM32F412xx/STM32F413xx devices.

HAL_FLASHEx_OB_GetBank2WRP

Function name

uint16_t HAL_FLASHEx_OB_GetBank2WRP (void)

Function description

Returns the FLASH Write Protection Option Bytes value for Bank 2.

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Return values

The: FLASH Write Protection Option Bytes value

Notes

This function can be used only for STM32F42xxx/STM32F43xxx/STM32F469xx/STM32F479xx devices.

FLASH_Erase_Sector

Function name

void FLASH_Erase_Sector (uint32_t Sector, uint8_t VoltageRange)

Function description

Erase the specified FLASH memory sector.

Parameters

- Sector: FLASH sector to erase The value of this parameter depend on device used within the same series
- VoltageRange: The device voltage range which defines the erase parallelism. This parameter can be one
 of the following values:
 - FLASH_VOLTAGE_RANGE_1: when the device voltage range is 1.8V to 2.1V, the operation will be done by byte (8-bit)
 - FLASH_VOLTAGE_RANGE_2: when the device voltage range is 2.1V to 2.7V, the operation will be done by half word (16-bit)
 - FLASH_VOLTAGE_RANGE_3: when the device voltage range is 2.7V to 3.6V, the operation will be done by word (32-bit)
 - FLASH_VOLTAGE_RANGE_4: when the device voltage range is 2.7V to 3.6V + External Vpp, the operation will be done by double word (64-bit)

Return values

None:

FLASH_FlushCaches

Function name

void FLASH FlushCaches (void)

Function description

Flush the instruction and data caches.

Return values

None:

27.3 FLASHEx Firmware driver defines

The following section lists the various define and macros of the module.

27.3.1 FLASHEX

FLASHEX

FLASH Advanced Option Type

OPTIONBYTE_PCROP

PCROP option byte configuration

OPTIONBYTE_BOOTCONFIG

BOOTConfig option byte configuration

FLASH Banks

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FLASH BANK 1

Bank 1

FLASH_BANK_2

Bank 2

FLASH_BANK_BOTH

Bank1 and Bank2

FLASH BOR Reset Level

OB_BOR_LEVEL3

Supply voltage ranges from 2.70 to 3.60 V

OB BOR LEVEL2

Supply voltage ranges from 2.40 to 2.70 V

OB BOR LEVEL1

Supply voltage ranges from 2.10 to 2.40 V

OB_BOR_OFF

Supply voltage ranges from 1.62 to 2.10 V

FLASH Dual Boot

OB_DUAL_BOOT_ENABLE

Dual Bank Boot Enable

OB_DUAL_BOOT_DISABLE

Dual Bank Boot Disable, always boot on User Flash

FLASH Private macros to check input parameters

IS_FLASH_TYPEERASE

IS_VOLTAGERANGE

IS_WRPSTATE

IS_OPTIONBYTE

IS_OB_RDP_LEVEL

IS_OB_IWDG_SOURCE

IS_OB_STOP_SOURCE

IS_OB_STDBY_SOURCE

IS_OB_BOR_LEVEL

IS_PCROPSTATE

IS_OBEX

IS_FLASH_LATENCY

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IS_FLASH_BANK

IS_FLASH_SECTOR

IS_FLASH_ADDRESS

IS_FLASH_NBSECTORS

IS_OB_WRP_SECTOR

IS_OB_PCROP

IS_OB_BOOT

IS_OB_PCROP_SELECT

FLASH Mass Erase bit

FLASH_MER_BIT

2 MER bits here to clear

FLASH Option Bytes IWatchdog

OB IWDG SW

Software IWDG selected

OB_IWDG_HW

Hardware IWDG selected

FLASH Option Bytes nRST_STDBY

OB_STDBY_NO_RST

No reset generated when entering in STANDBY

OB_STDBY_RST

Reset generated when entering in STANDBY

FLASH Option Bytes nRST_STOP

OB_STOP_NO_RST

No reset generated when entering in STOP

OB_STOP_RST

Reset generated when entering in STOP

FLASH Option Bytes PC ReadWrite Protection

OB_PCROP_SECTOR_0

PC Read/Write protection of Sector0

OB_PCROP_SECTOR_1

PC Read/Write protection of Sector1

OB_PCROP_SECTOR_2

PC Read/Write protection of Sector2

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OB_PCROP_SECTOR_3

PC Read/Write protection of Sector3

OB_PCROP_SECTOR_4

PC Read/Write protection of Sector4

OB_PCROP_SECTOR_5

PC Read/Write protection of Sector5

OB_PCROP_SECTOR_6

PC Read/Write protection of Sector6

OB_PCROP_SECTOR_7

PC Read/Write protection of Sector7

OB_PCROP_SECTOR_8

PC Read/Write protection of Sector8

OB_PCROP_SECTOR_9

PC Read/Write protection of Sector9

OB_PCROP_SECTOR_10

PC Read/Write protection of Sector10

OB_PCROP_SECTOR_11

PC Read/Write protection of Sector11

OB_PCROP_SECTOR_12

PC Read/Write protection of Sector12

OB_PCROP_SECTOR_13

PC Read/Write protection of Sector13

OB_PCROP_SECTOR_14

PC Read/Write protection of Sector14

OB_PCROP_SECTOR_15

PC Read/Write protection of Sector15

OB_PCROP_SECTOR_16

PC Read/Write protection of Sector16

OB_PCROP_SECTOR_17

PC Read/Write protection of Sector17

OB_PCROP_SECTOR_18

PC Read/Write protection of Sector18

OB_PCROP_SECTOR_19

PC Read/Write protection of Sector19

OB_PCROP_SECTOR_20

PC Read/Write protection of Sector20

OB_PCROP_SECTOR_21

PC Read/Write protection of Sector21

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OB_PCROP_SECTOR_22
             PC Read/Write protection of Sector22
OB_PCROP_SECTOR_23
             PC Read/Write protection of Sector23
OB_PCROP_SECTOR_AII
             PC Read/Write protection of all Sectors
            FLASH Option Bytes Read Protection
OB_RDP_LEVEL_0
OB_RDP_LEVEL_1
OB_RDP_LEVEL_2
             Warning: When enabling read protection level 2 it s no more possible to go back to level 1 or 0
            FLASH Option Bytes Write Protection
OB_WRP_SECTOR_0
             Write protection of Sector0
OB_WRP_SECTOR_1
             Write protection of Sector1
OB_WRP_SECTOR_2
             Write protection of Sector2
OB WRP SECTOR 3
             Write protection of Sector3
OB_WRP_SECTOR_4
             Write protection of Sector4
OB_WRP_SECTOR_5
             Write protection of Sector5
OB_WRP_SECTOR_6
             Write protection of Sector6
OB_WRP_SECTOR_7
             Write protection of Sector7
OB_WRP_SECTOR_8
             Write protection of Sector8
OB_WRP_SECTOR_9
             Write protection of Sector9
OB_WRP_SECTOR_10
             Write protection of Sector10
OB_WRP_SECTOR_11
             Write protection of Sector11
OB_WRP_SECTOR_12
             Write protection of Sector12
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OB_WRP_SECTOR_13

Write protection of Sector13

OB_WRP_SECTOR_14

Write protection of Sector14

OB_WRP_SECTOR_15

Write protection of Sector15

OB_WRP_SECTOR_16

Write protection of Sector16

OB_WRP_SECTOR_17

Write protection of Sector17

OB_WRP_SECTOR_18

Write protection of Sector18

OB_WRP_SECTOR_19

Write protection of Sector19

OB_WRP_SECTOR_20

Write protection of Sector20

OB_WRP_SECTOR_21

Write protection of Sector21

OB_WRP_SECTOR_22

Write protection of Sector22

OB_WRP_SECTOR_23

Write protection of Sector23

OB_WRP_SECTOR_AII

Write protection of all Sectors

FLASH Option Type

OPTIONBYTE_WRP

WRP option byte configuration

OPTIONBYTE_RDP

RDP option byte configuration

OPTIONBYTE_USER

USER option byte configuration

OPTIONBYTE_BOR

BOR option byte configuration

FLASH PCROP State

OB PCROP STATE DISABLE

Disable PCROP

OB_PCROP_STATE_ENABLE

Enable PCROP

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FLASH Sectors

FLASH_SECTOR_0

Sector Number 0

FLASH_SECTOR_1

Sector Number 1

FLASH_SECTOR_2

Sector Number 2

FLASH_SECTOR_3

Sector Number 3

FLASH_SECTOR_4

Sector Number 4

FLASH_SECTOR_5

Sector Number 5

FLASH_SECTOR_6

Sector Number 6

FLASH_SECTOR_7

Sector Number 7

FLASH_SECTOR_8

Sector Number 8

FLASH_SECTOR_9

Sector Number 9

FLASH_SECTOR_10

Sector Number 10

FLASH_SECTOR_11

Sector Number 11

FLASH_SECTOR_12

Sector Number 12

FLASH_SECTOR_13

Sector Number 13

FLASH_SECTOR_14

Sector Number 14

FLASH_SECTOR_15

Sector Number 15

FLASH_SECTOR_16

Sector Number 16

FLASH_SECTOR_17

Sector Number 17

FLASH_SECTOR_18

Sector Number 18

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FLASH SECTOR 19

Sector Number 19

FLASH_SECTOR_20

Sector Number 20

FLASH_SECTOR_21

Sector Number 21

FLASH_SECTOR_22

Sector Number 22

FLASH_SECTOR_23

Sector Number 23

FLASH Selection Protection Mode

OB PCROP DESELECTED

Disabled PcROP, nWPRi bits used for Write Protection on sector i

OB_PCROP_SELECTED

Enable PcROP, nWPRi bits used for PCRoP Protection on sector i

FLASH Type Erase

FLASH_TYPEERASE_SECTORS

Sectors erase only

FLASH_TYPEERASE_MASSERASE

Flash Mass erase activation

FLASH Voltage Range

FLASH_VOLTAGE_RANGE_1

Device operating range: 1.8V to 2.1V

FLASH_VOLTAGE_RANGE_2

Device operating range: 2.1V to 2.7V

FLASH_VOLTAGE_RANGE_3

Device operating range: 2.7V to 3.6V

FLASH_VOLTAGE_RANGE_4

Device operating range: 2.7V to 3.6V + External Vpp

FLASH WRP State

OB_WRPSTATE_DISABLE

Disable the write protection of the desired bank 1 sectors

OB_WRPSTATE_ENABLE

Enable the write protection of the desired bank 1 sectors

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